NSN 5961-01-231-3389

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View Online at https://aerobasegroup.com/nsn/5961-01-231-3389 **Inclosure Material:** Metal **Overall Length:** 400.0 millimeters **Overall Height:** 110.0 millimeters **Overall Width:** 250.0 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 collector to base voltage/static/emitter open and 180.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and -15.00 amperes source cutoff current blank **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Transfer Ratio:** 140.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

No Fiig:

Demilitarization:

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